

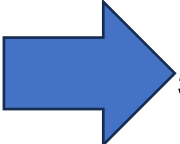
# The development of a laser system for use in the timing performance measurements of CMS HGCAL silicon modules.

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CERN / Université Libre de Bruxelles

On behalf of the CMS Collaboration

TWEPP, 2–6 Oct 2023, Geremeas, Sardinia, Italy

1. Performance of H2GCROC3, the readout ASIC of SiPMs for the back hadronic sections of the CMS High Granularity Calorimeter, by Jose David Gonzalez .
2. First test results for ECON-T and ECON-D ASICs for CMS HGCAL, by Cristina Ana Mantilla Suarez.
3. The CMS HGCAL trigger data receiver, by Raghunandan Shukla.
4. CMS HGCAL Electronics Vertical Integration System Tests, Poster by Milos Vojinovic.
-  5. The development of a laser system for use in the timing performance measurements of CMS HGCAL silicon modules, this talk.

# HGCAL : High Granularity Calorimeter

The HGCAL is the 47-layer sampling Calorimeter that will replace the existing ECAL (PbWO<sub>4</sub> crystal) & HCAL (plastic scintillator) Endcap calorimeters in Phase-II upgrades for High Luminosity Large Hadron Collider (HL-LHC).

**Two parts:**

CE-E (electromagnetic)

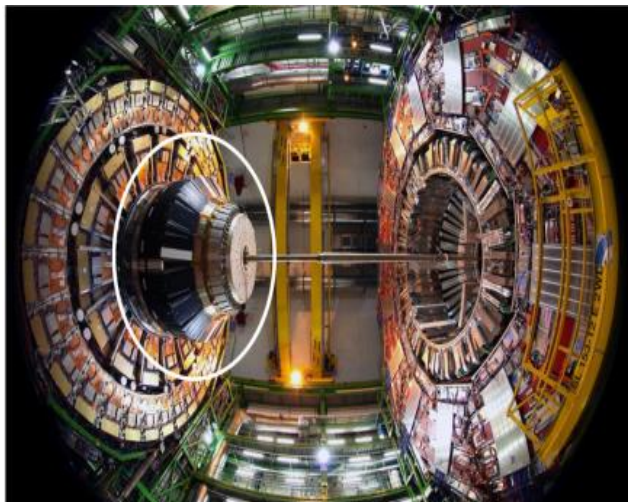
CE-H (hadronic)

**Active materials:**

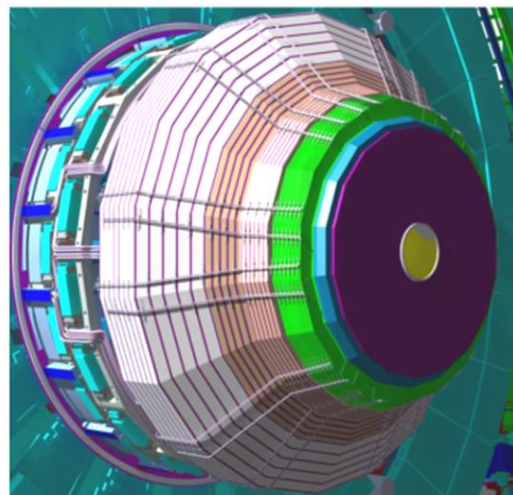
620 m<sup>2</sup> of Silicon in CE-E and high rad. zone of CE-H

370 m<sup>2</sup> of Scintillator tiles with SiPM in low-rad. region

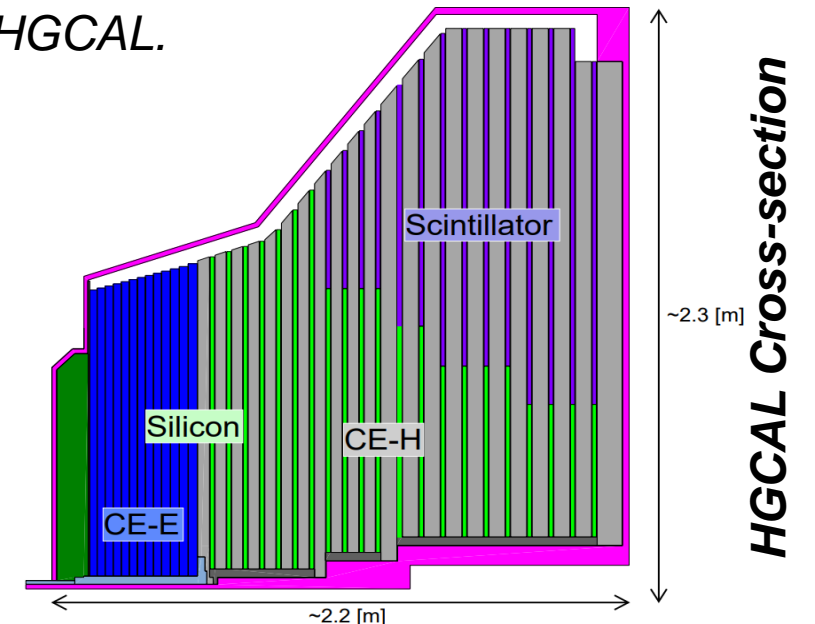
*Our work is relevant to the testing of modules for silicon region of HGCAL.*



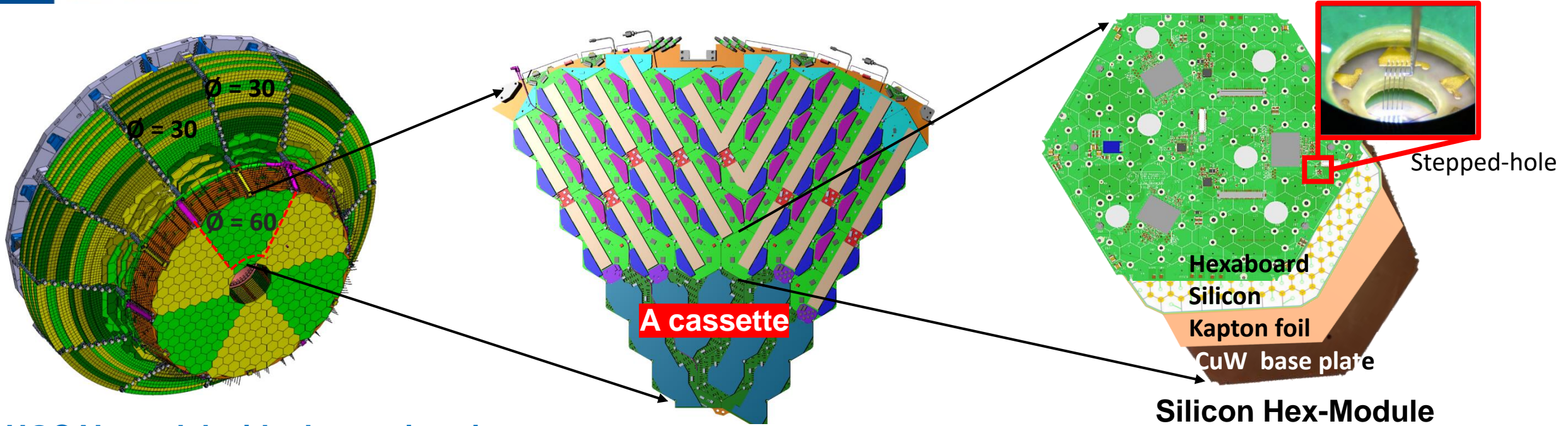
**Existing Endcap Calorimeter**



**HGCAL model**



**HGCAL Cross-section**



## HGCAL model with electronics view

A cassette is

$60^\circ$  (1/6) in CE-E layer  
 $30^\circ$  (1/12) of layer CE-H.

- ❑ Instrumented with Silicon-Hex- Modules.
- ❑ Superimposed by supporting electronics boards.

## Silicon Hex-Module (Qty: ~26,000)

- ❑ Glued assembly of base-plate, Kapton foil, **Silicon sensor & Hexaboard**,
- ❑ The bonding pads connected to ASIC are bonded to silicon sensor via stepped holes.

## Silicon Hex-Module

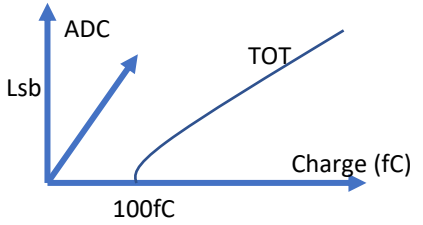
- ❑ Hosts upto 06 **HGCROC** ASICs
- ❑ Large dynamic range  $0.2fC \rightarrow 10 pC$
- ❑ Trigger Primitive generation
- ❑ **Measure TOA (time of arrival) for charge > 12fC**

See Performance of H2GCROC3, the readout ASIC of SiPMs for the back hadronic sections of the CMS High Granularity Calorimeter. by **Jose David Gonzalez**

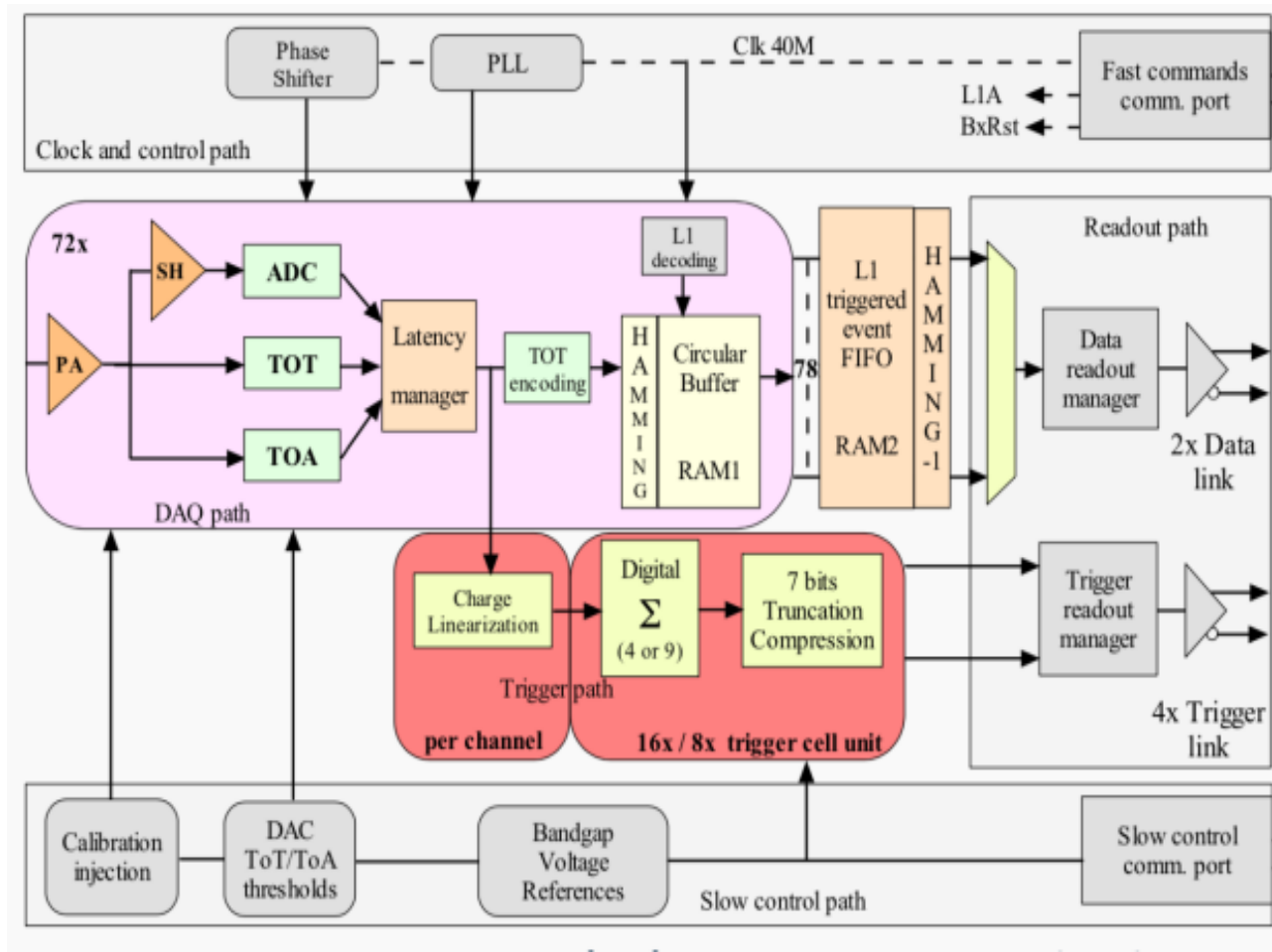
HGCROC is the readout ASICs used on Hexaboard.

Dynamic Range ~0.2fC to 10pC  
 ENC < 2500e (Cd=65pF)  
 Shaping Time ~20ns  
 Linearity <1%  
 Pos. & Neg input charge

**Energy Measurement**  
 ADC 10b SAR  
 range 0 > 100fC (150fC)  
 TOT range 100fC > 10pC  
 TOT bin size 2.5fC

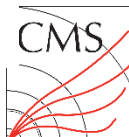


**Time Of Arrival (TOA)**  
 10b TDC  
 lsb <25ps, 25ns full range



- Comm port**
  - 320MHz clock
  - Reception of fast commands through lpGBT
- Data Readout Path**
  - Data packets after L1A
  - L1A latency up to 12.5us
  - 2 SLVS outputs @ 1.28Gbps
- Trigger readout Path**
  - Trigger cells (2x2/3x3)
  - 4 SLVS outputs @ 1.28 Gb/s
- Slow Control**
  - Programmable registers
  - I2C protocol

HGCROCV3 Block Diagram

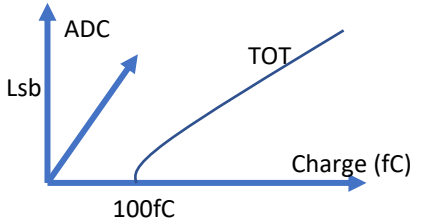


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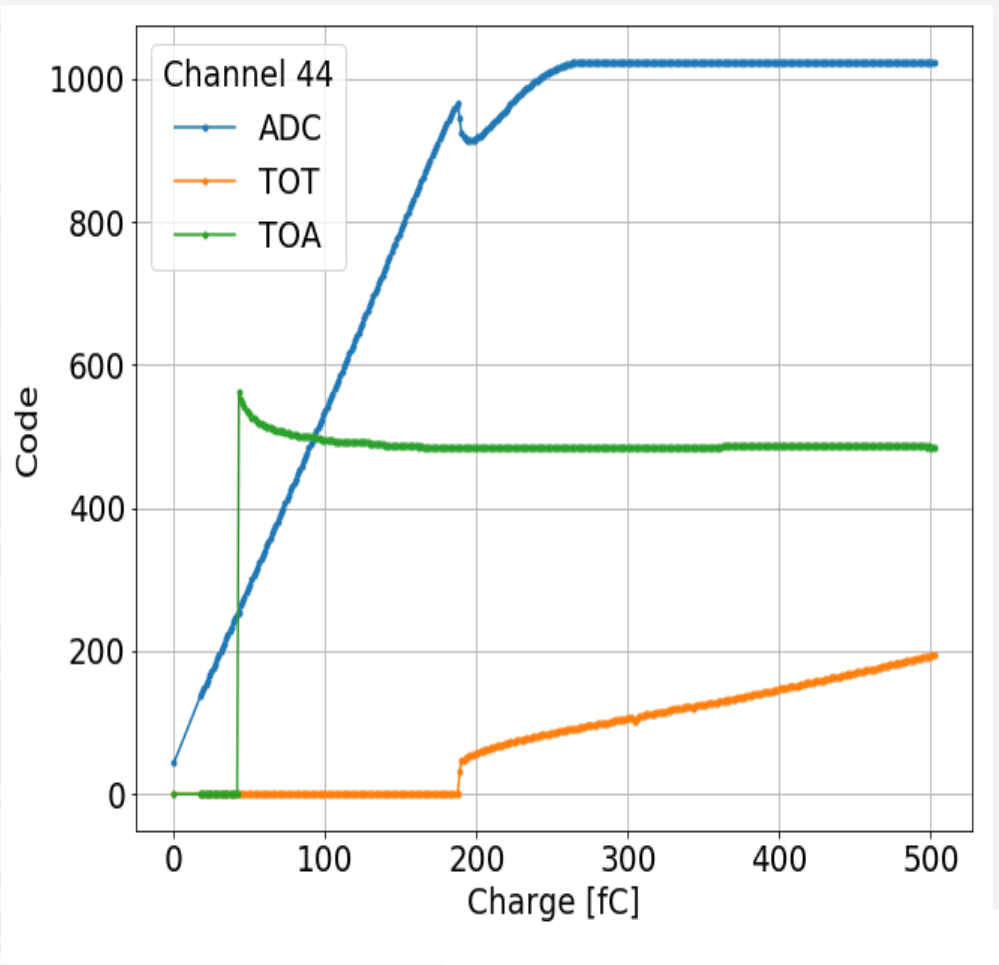
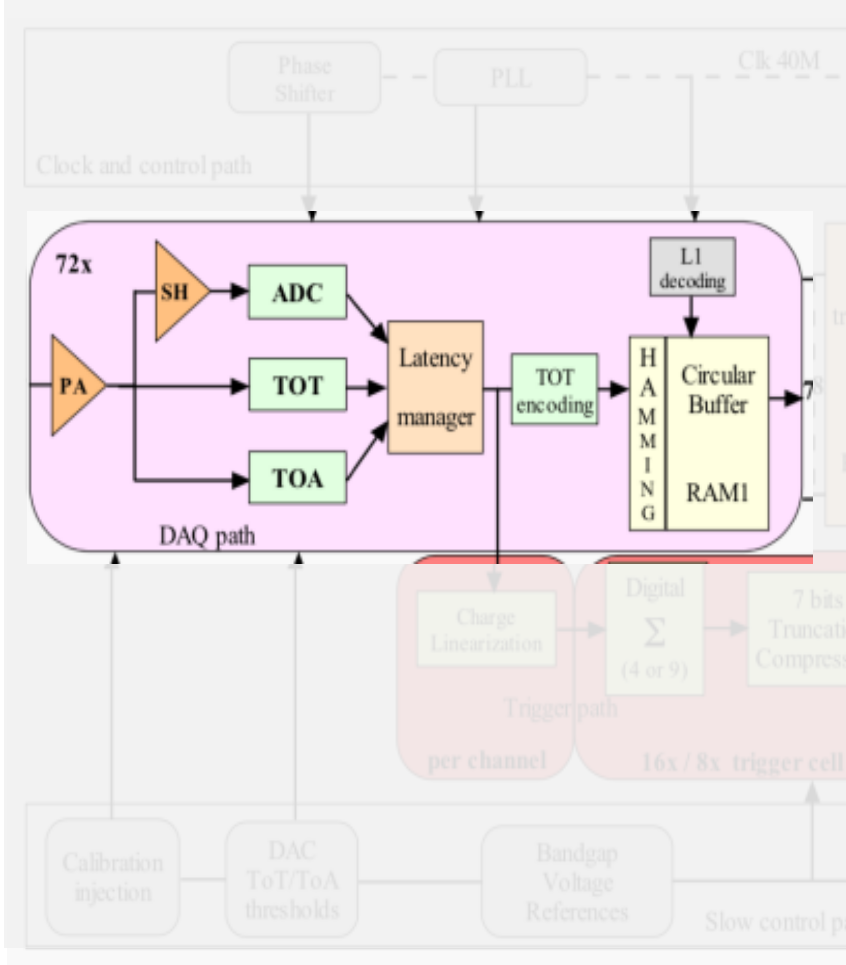
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HGCROCV3 Block Diagram



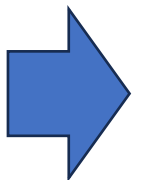
# Three complementary setups (methods) for the module tests

## 1: Charge Injection by External Capacitor:

- For test board level characterization.
- Fixed hardware, possible inconsistency of impedance

## 2: Beam Test:- (The realistic environment)

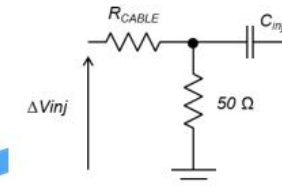
- Real charge distribution in the Si sensor by known particles.
- Limited time, Needs a lot of logistic and person power



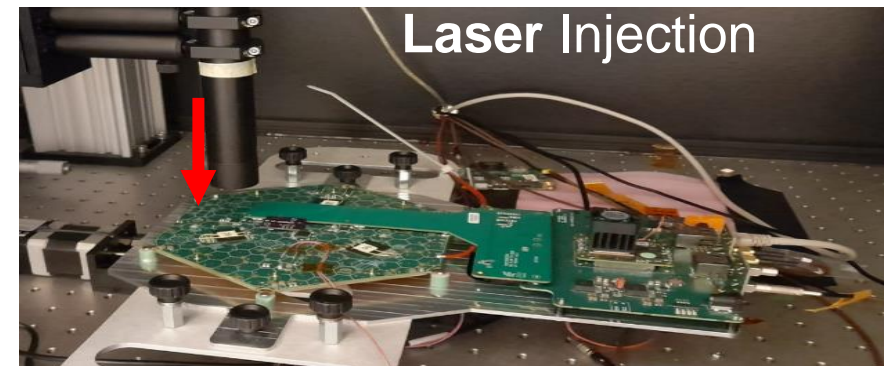
## 3: Charge Injection by Laser:

**Injecting** Laser in silicon cell includes

- whole path (sensor+ readout circuitry)
- repeatable, easy access in the lab, easy DAQ system.
- In <100 ps accurate test system is not simple.



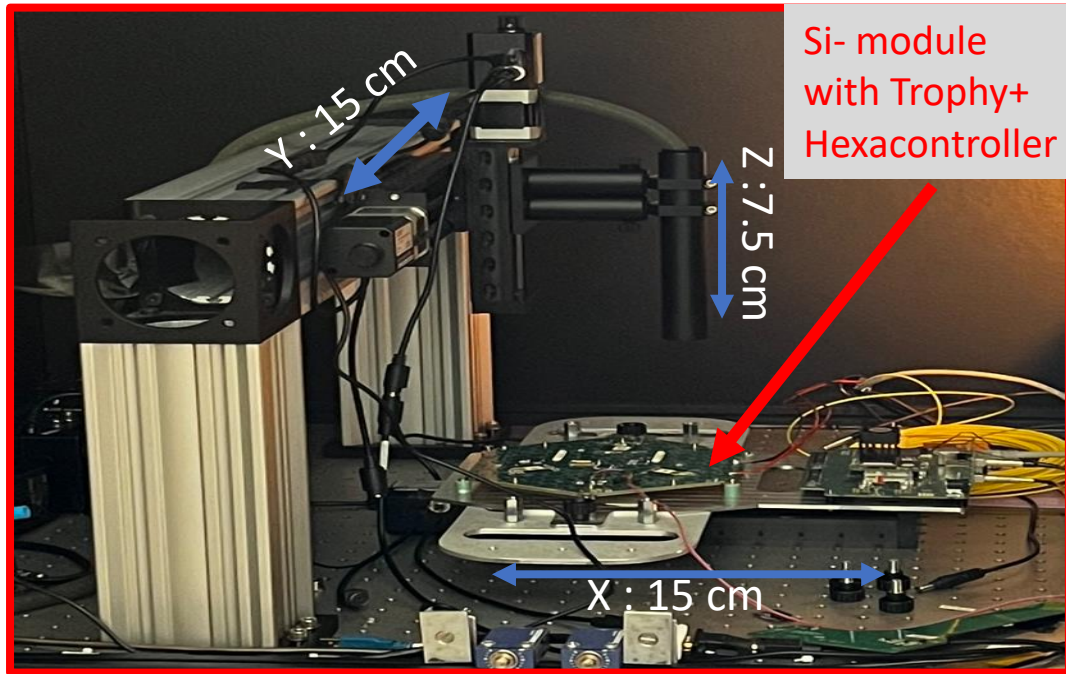
$$Q_{inj} = C_{inj} \times \Delta V_{inj}$$



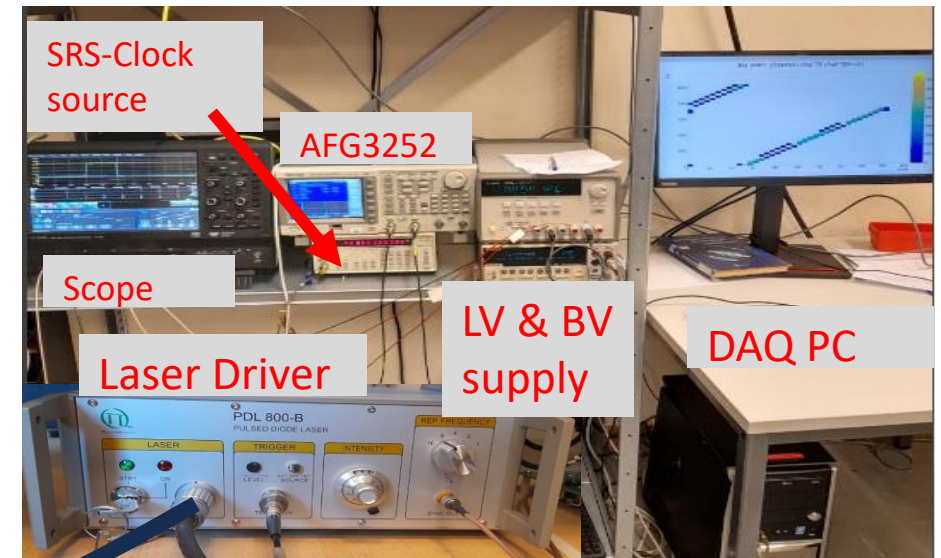
- ❑ ~26,000 module in 11 variants..
- ❑ < 100 ps resolution,
- ❑ Large dynamic range (0.2fC → 10 pC)
- ❑ A test system with precise control over time & charge injection is required.

- ❑ We developed a laser system for the Silicon Modules characterization(legacy of NA62, we modified it for HGCal setup)

**Laser**  $\lambda=1064$  nm, FWHM = 100 ps  
**Automated:** X, Y, Z stage with 0.5um step & Optical Attenuator (2.58 → 50 dB)



Si- module with Trophy+ Hexacontroller



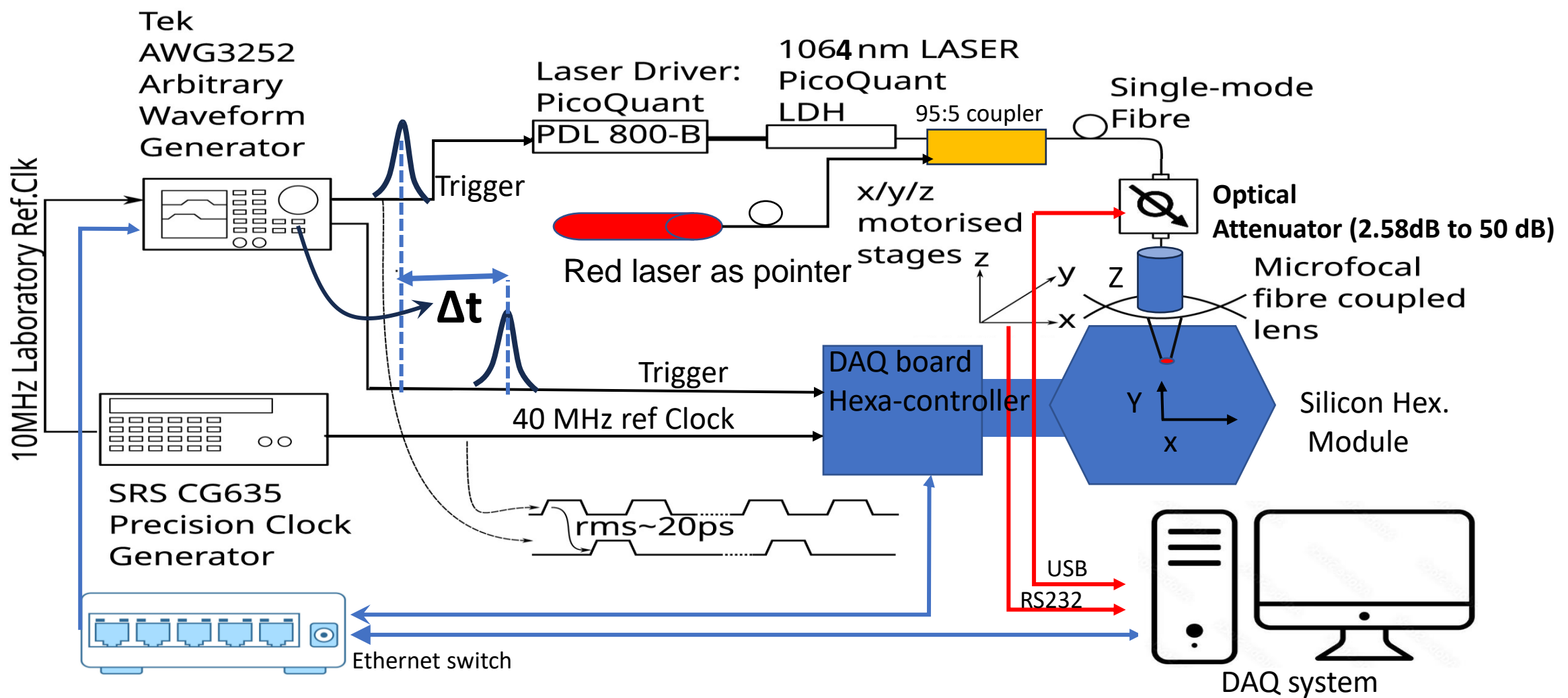
Laser-setup's parts out of the dark room (cabin)

For safety purpose: All optical components & Interconnects are inside dark room type cabin

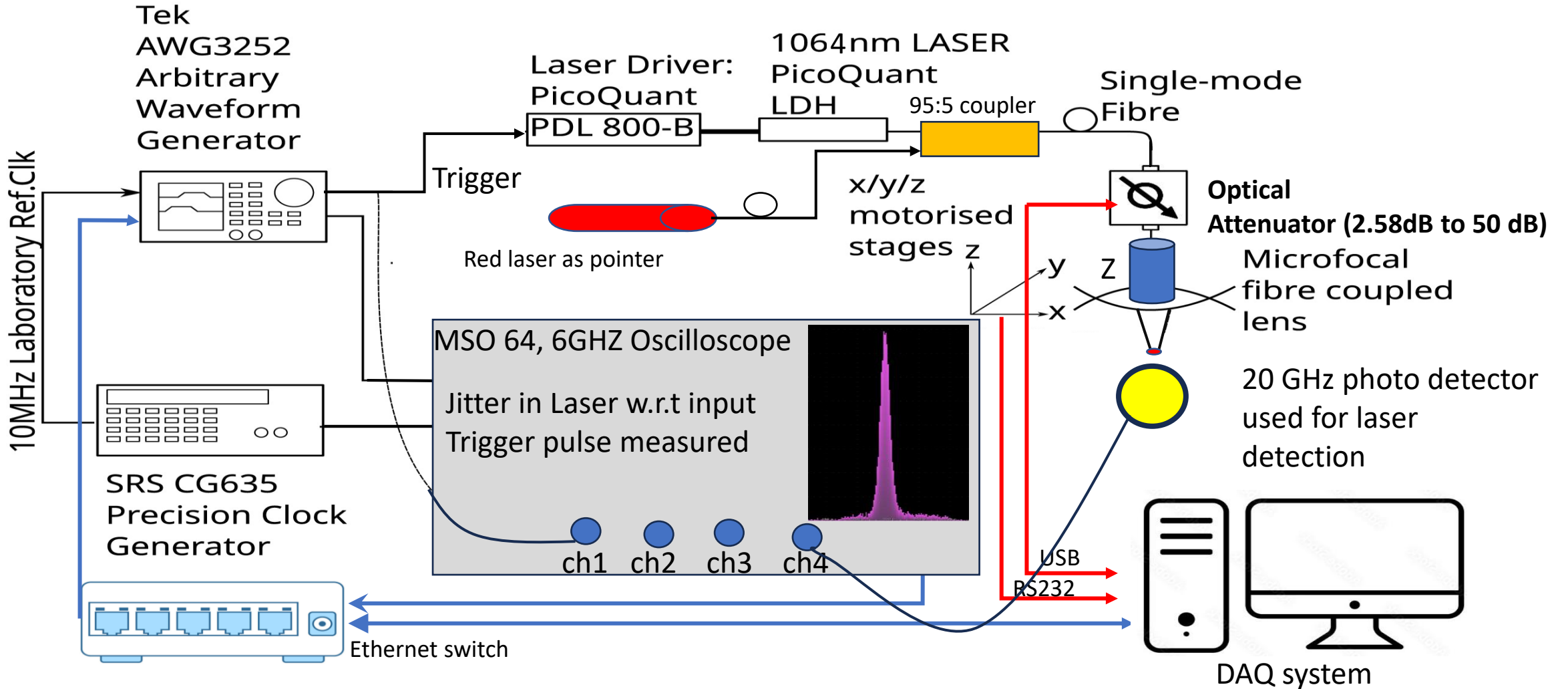


# Laser test system for Si-module characterization

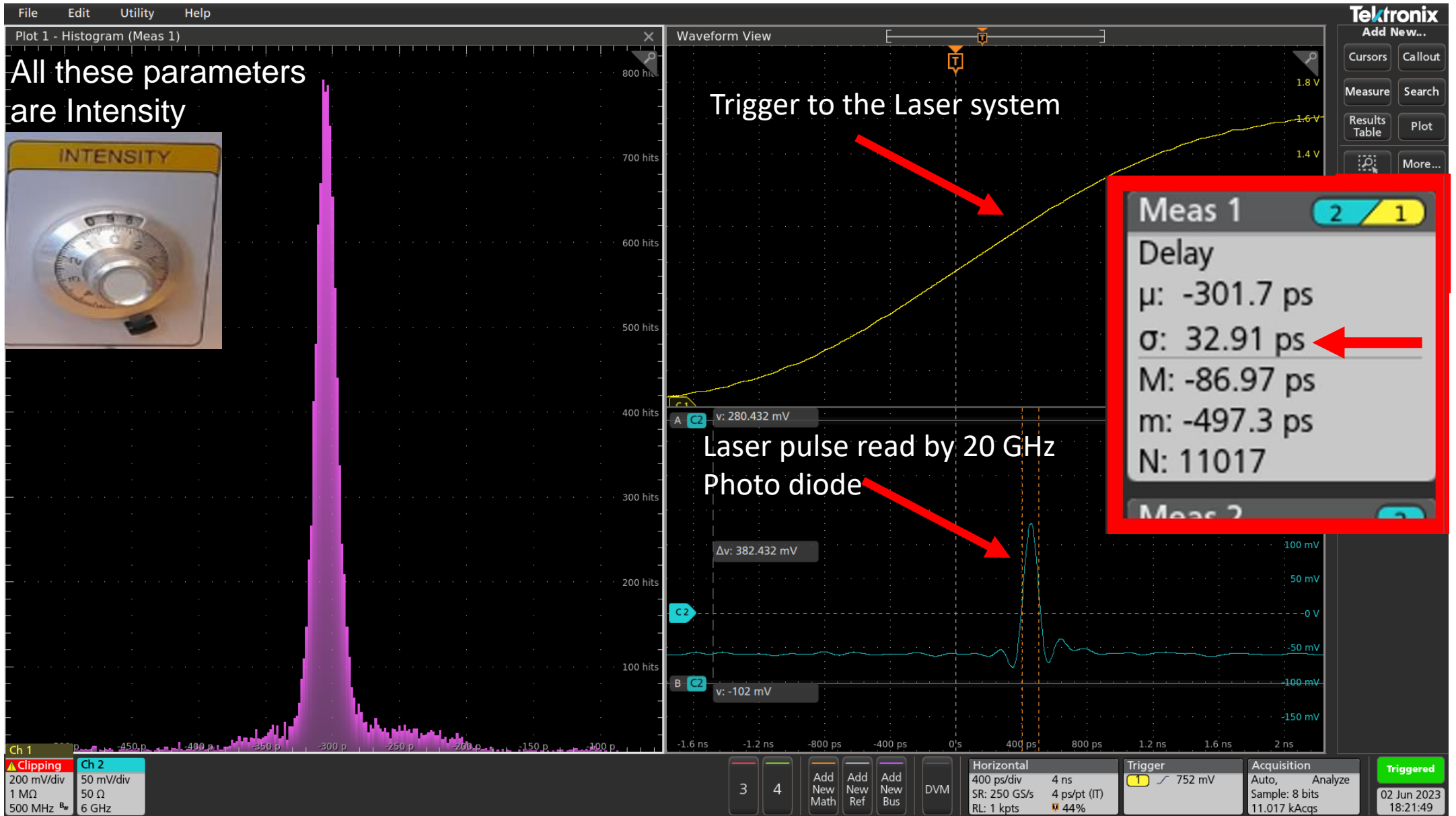
## Block diagram

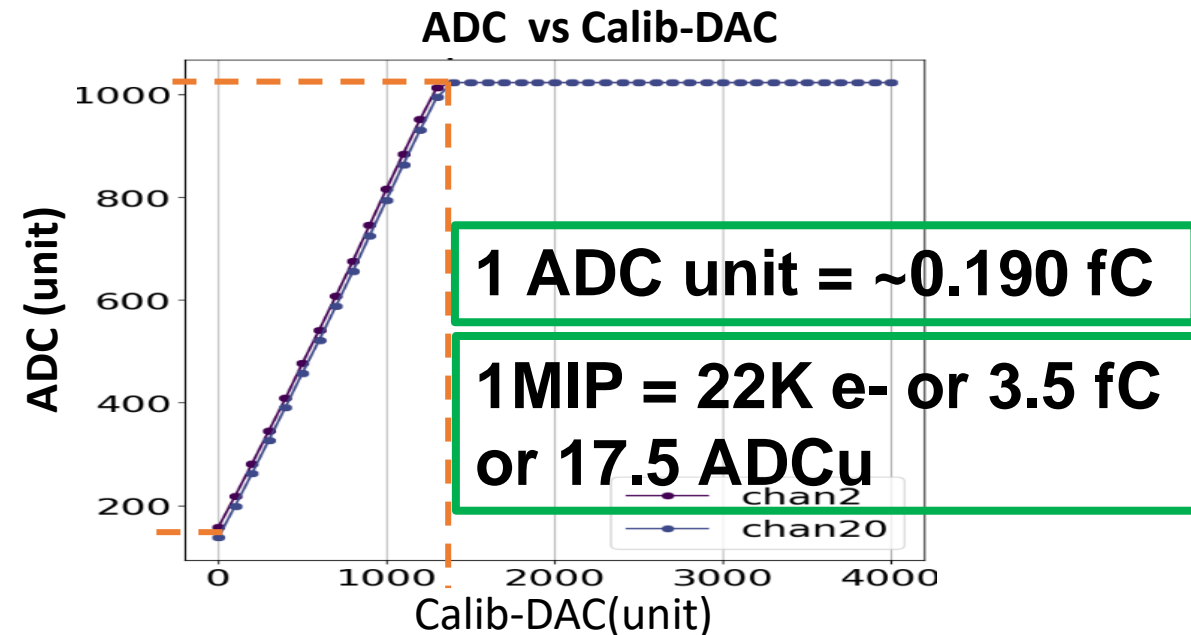
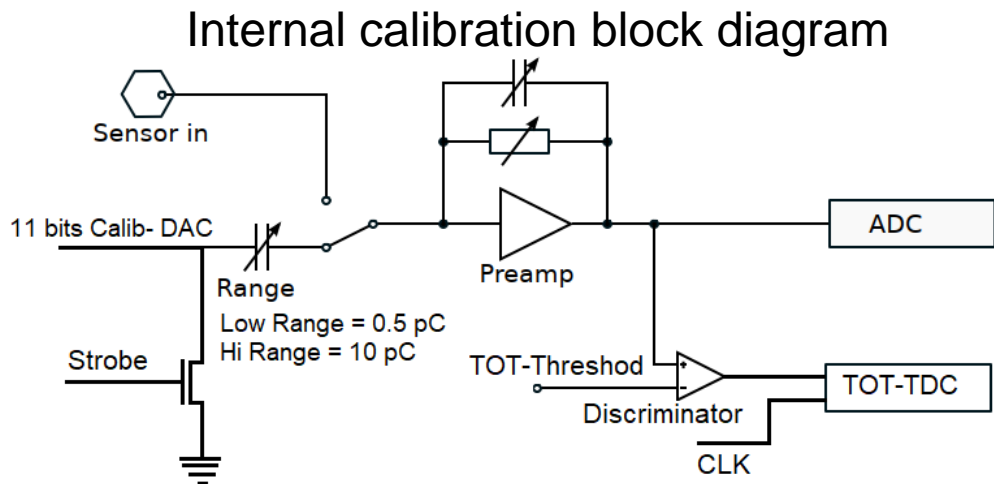


# Laser system jitter measurements



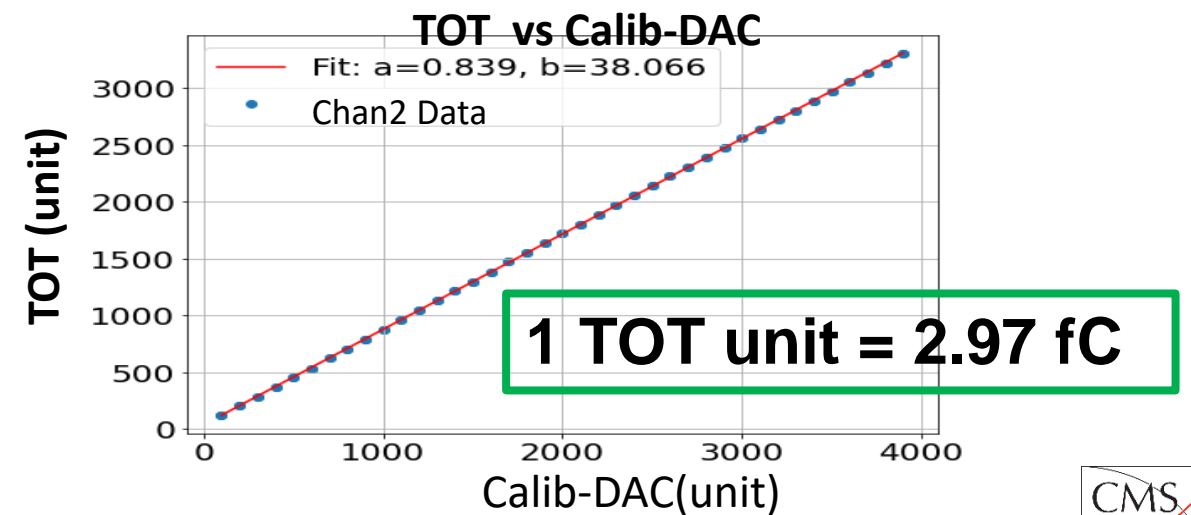
# Laser has ~ 33 ps jitter w.r.t Laser Trigger





## Two modes

- 1) ADC calibration:  
500 fF Cap used to inject 500fC charge .
- 2) TOT (Time over Threshold) region:  
10 pC charge injected via 10 pF Cap.

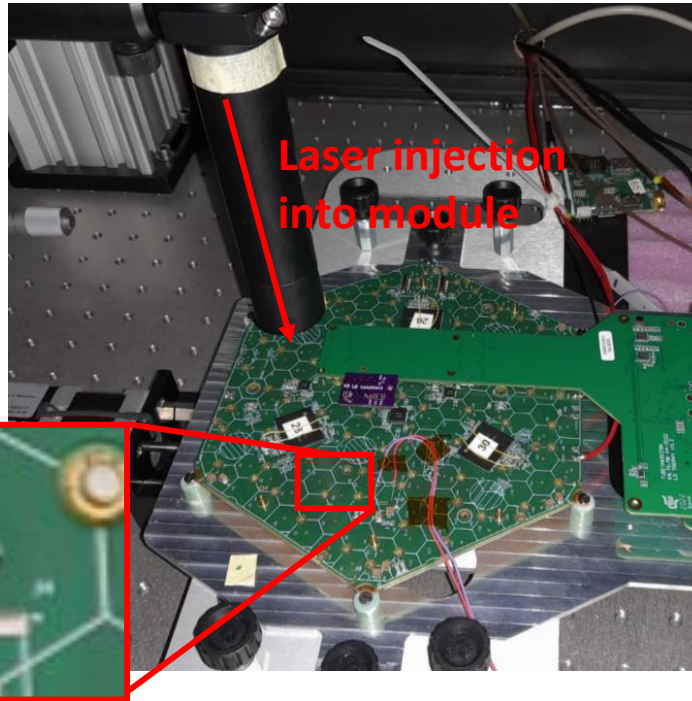


# Charge Injection into Si-module by Laser

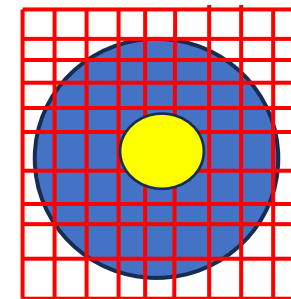
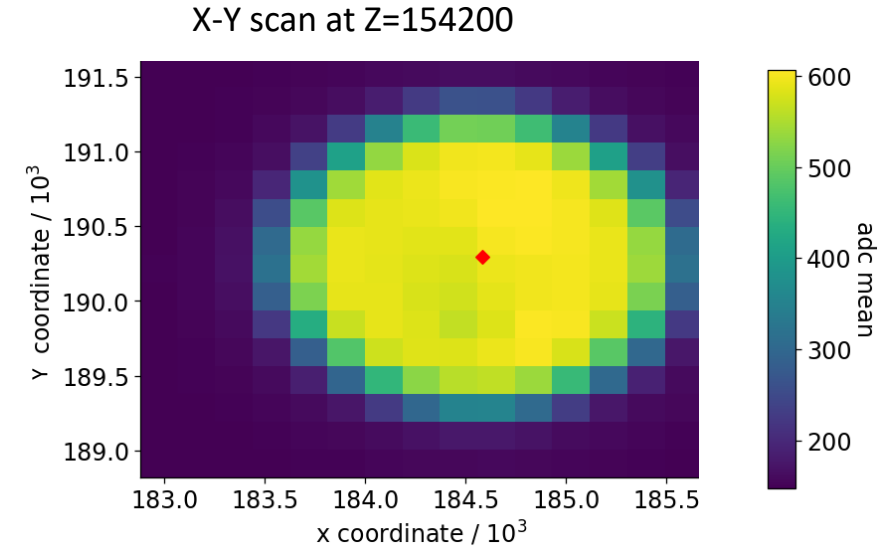
Laser light is injected into the silicon module by holes in the center of cell of the Hexaboard



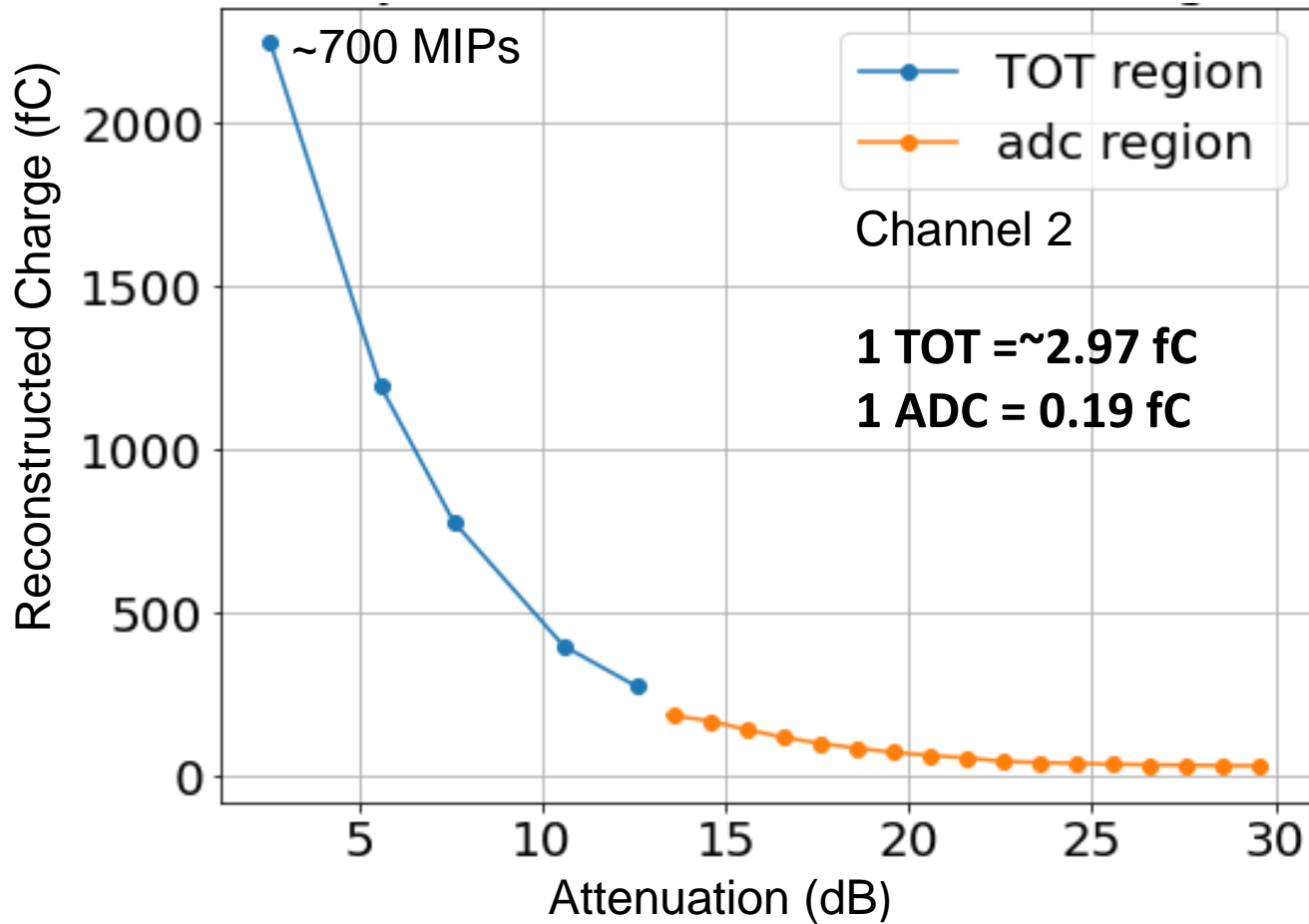
Silicon sensor with metallization opening(hole) in center of each cell, where laser can be injected



Hole in Hexaboard align to hole in Si are used for injection.



With X & Z stages, Laser Scanning the module cell in the form of a mesh and find out exact center



- ❑ The values of charge injected by Laser are calibrated with ADC and TOT conversion values we got by internal calibration.
- ❑ Provide charge variation with 0.01 dB step, ranging from 2.58 db to 50 dB.
- ❑ The Max. charge value at 2.58 dB corresponds to ~700 MIPs
- ❑ **Precise control on injected charge (0.01 dB) and laser timing (~30 ps) makes it clean environment for silicon modules characterization.**

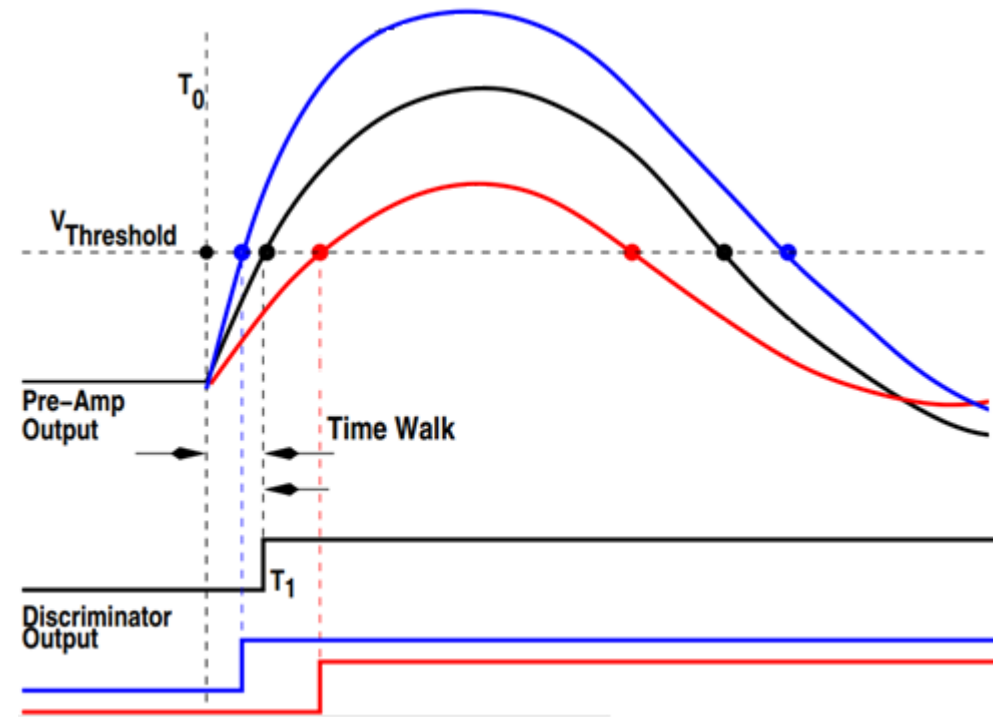
## Time-walk:

The dependence of measured time intervals (or time differences) of incoming signal or events on the amplitudes or shapes of the input signals.

## Effect in HGCROC:

Time-walk systematically shifts the time of arrival discriminator signal earlier as the signal charge increases.

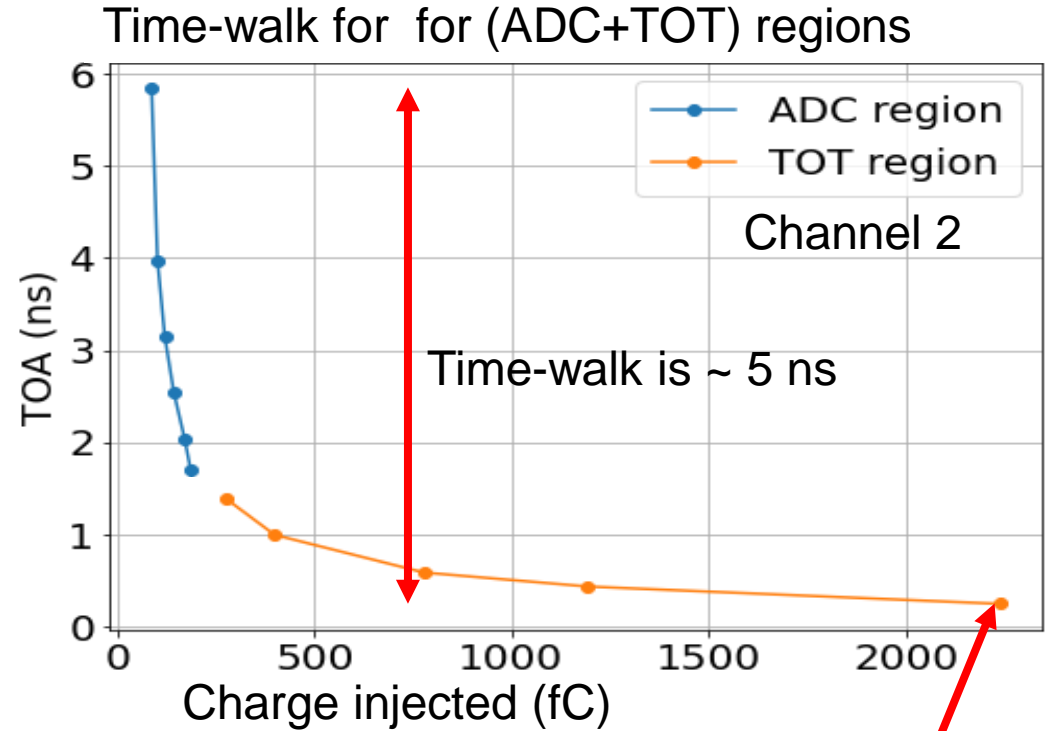
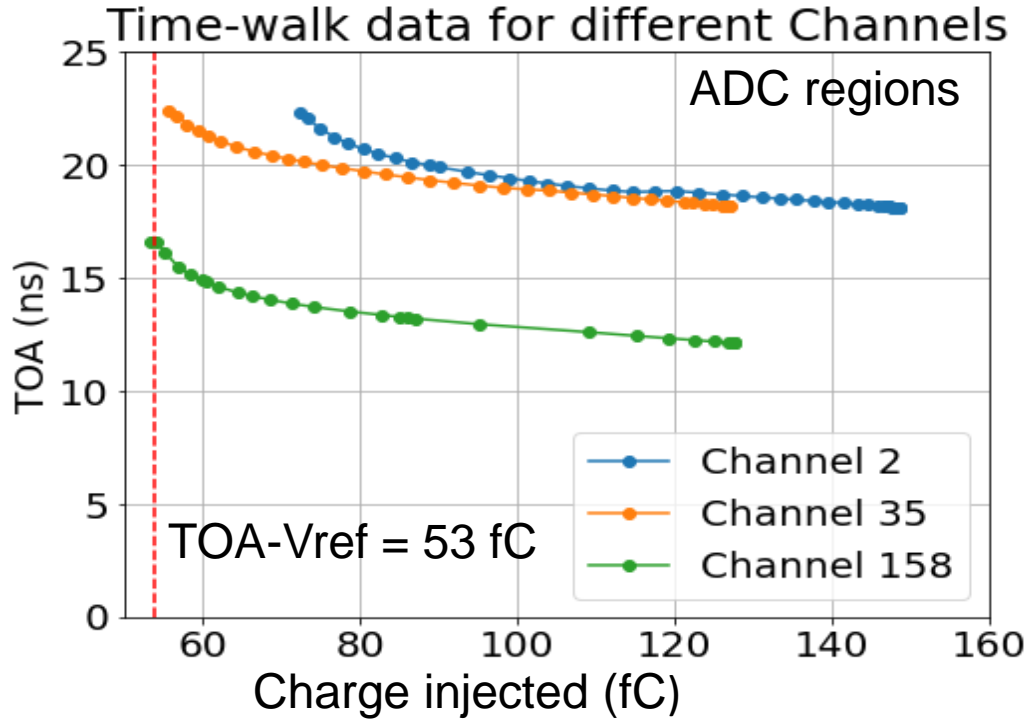
This is due to the signal increased slew rate.



Three signals with different amplitudes crossed same threshold, give three different Time of arrivals at discriminator

# Time-Walk study of Silicon Module

Time-walk curves can be produced by injected laser light and varying its intensity by attenuator.



- ❑ **Pk-Pk shift approx. 5ns**  
→ we must correct for it using the charge measurement.
- ❑ Time-walk curve be produced for any cell (within the mechanical limits of X-Y stage) of the silicon module.

Max Q-injected by Laser @2.58 dB  
~700 MIPs



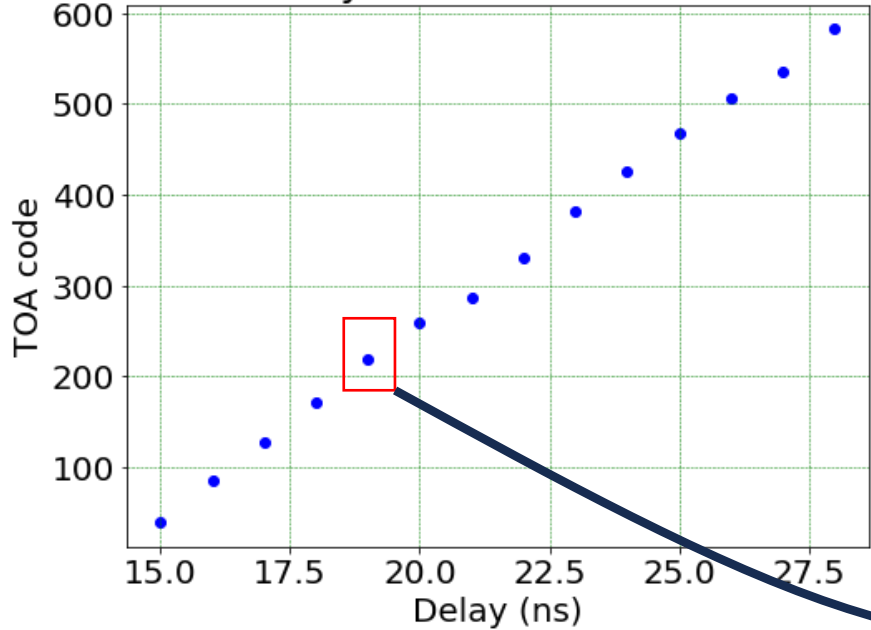
# TOA Calibration's validation (automation is in progress)

Waveform Generator (AFG3252) has minimum delay step of 10 ps, that will be used for TOA calibration confirmation.

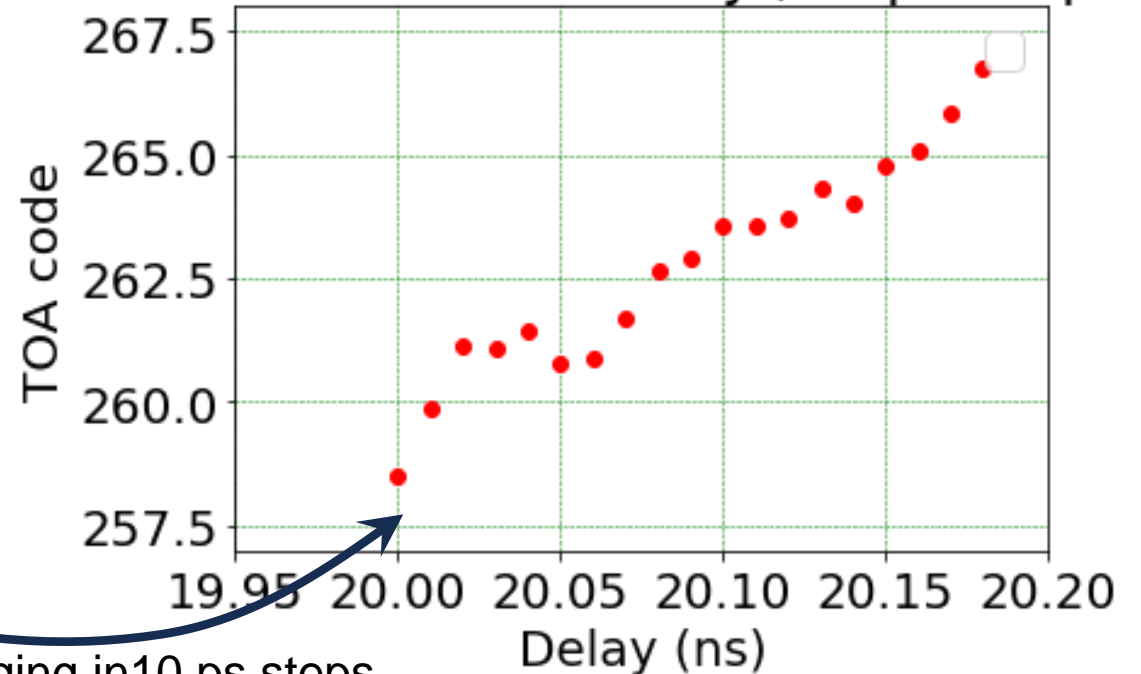
**Delay (AFG3252)  $\leftrightarrow$  linear  $\rightarrow$  TOA code value.**

Note:-Currently we did it manually just to show the method, for full range of BX to scan with 10 ps step, we need 2500 value, automation is in progress. **The plot showed for un-calibrated TOA**

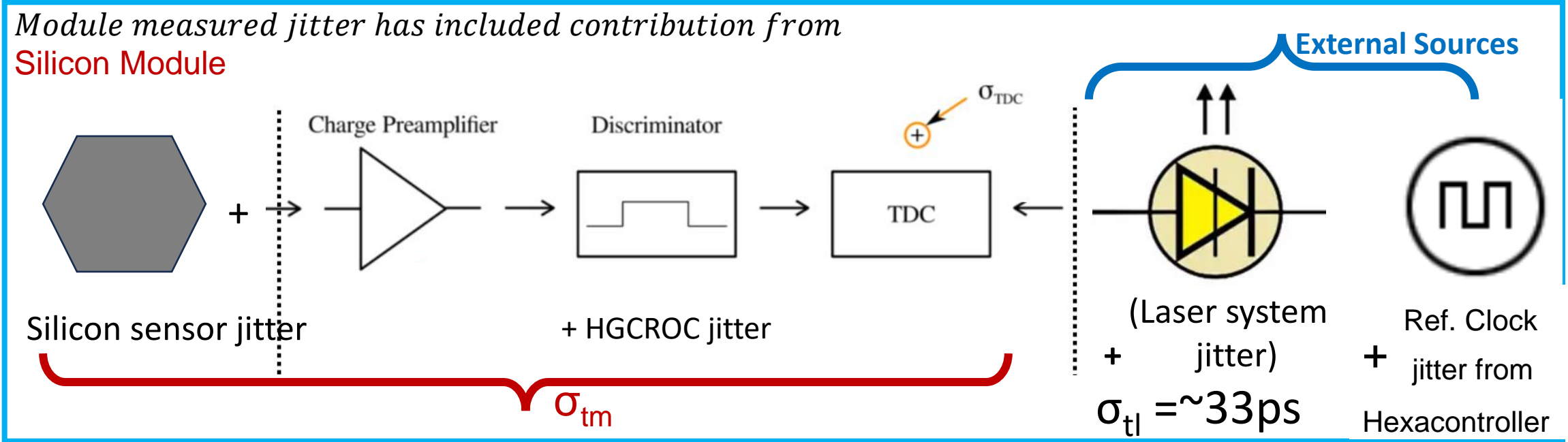
TOA code vs Delay between Laser & Hexacontroller



TOA code vs Delay ,10 ps step



Delay changing in 10 ps steps around this point



Next steps are

- TOA calibration has to be implemented
- Ref. Clock jitter to be measured.

$$\text{Module Jitter } (\sigma_{tm}) = \sqrt{(\text{module measured jitter})^2 - (\text{Laser system jitter})^2 - (\text{Module ref. clock jitter})^2}$$

- ❑ HGCAL is 47-layer sampling Calorimeter that will be installed in LS3.
- ❑ ~26,000 silicon module will be produced for Silicon region of HGCAL
- ❑ Stringent specifications, many variants, huge production volume demands to have a reliable and precise module characterization system.
- ❑ The Laser system developed, with low jitter (30 ps) and control energy 0.01 dB energy steps and upto ~2 pC charge, capable to scan Silicon module ( by x, y, z stages), will be used for silicon module characterization.
- ❑ The wide energy range (2 pC) gives us provision to use optical coupler or beam splitter to transform this to multichannel setup.

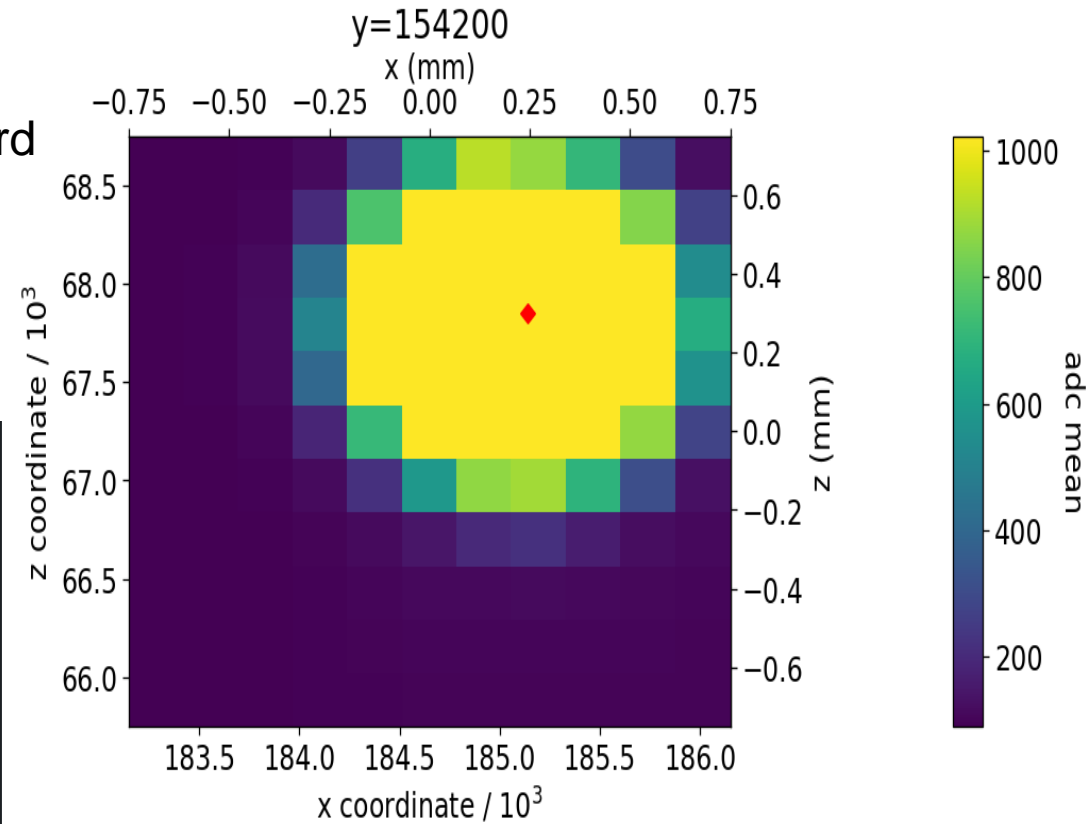
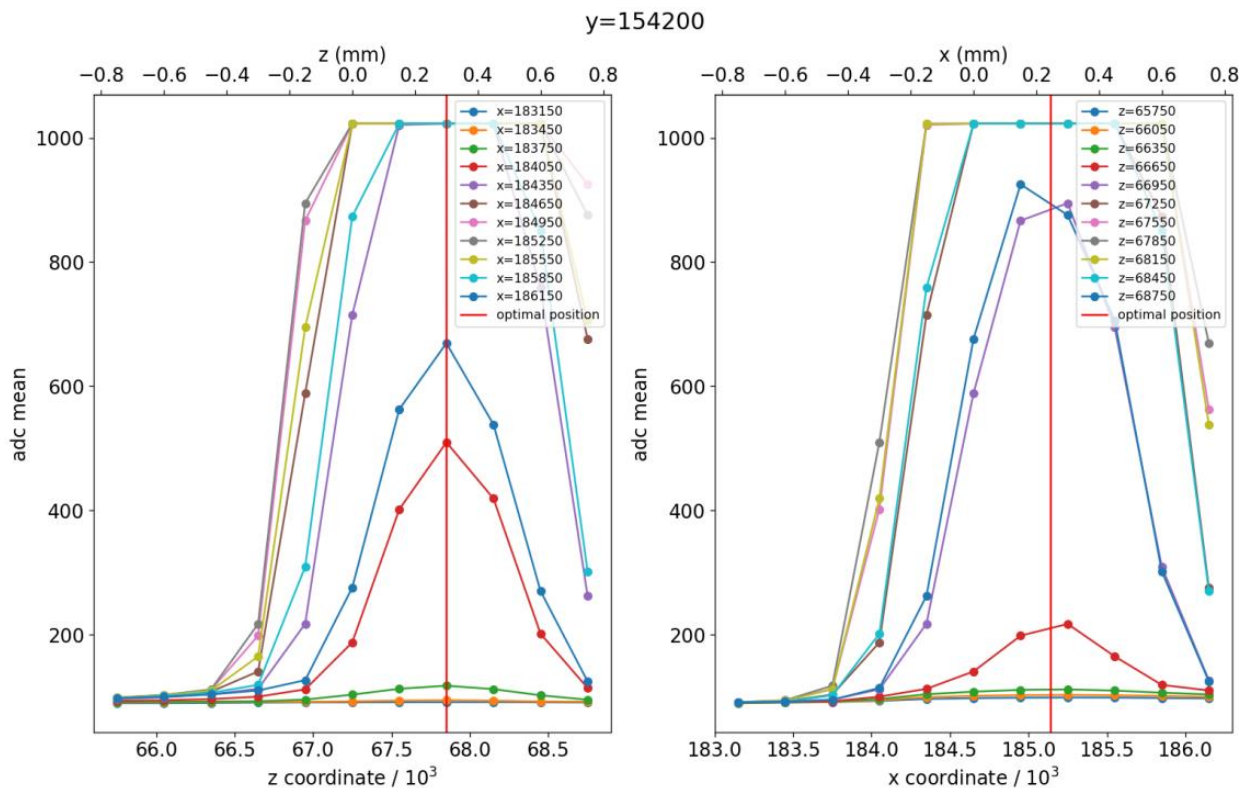
**THANKS**  
for your attention

# Backup

# Table Calibration, finding exact center of cell

We scan the opening in si- cell through the hole in Hexaboard using Laser X,Z stage. (Y is the collimation axis, it is fixed to closest position to silicon module Y=154200)

We start with an approximate location and the Laser system scan the area in the vicinity to final exact enter of the si- cell



Fields

Column type:

	Standard	Standard	Standard	Standard	Standard	Standard	Standard
	chan_id	chip	channel	half	x	y	z
1	35	0	35	0	185141	154200	67849
2							

# Charge calibration (ADC region)

For typical gain of 160 fC 1ADC unit = 0.190 fC

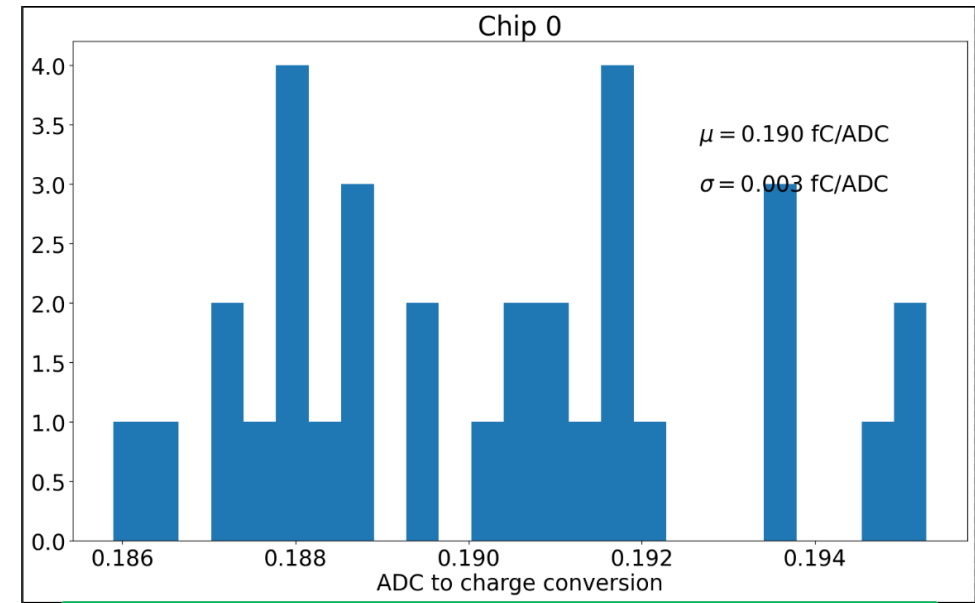
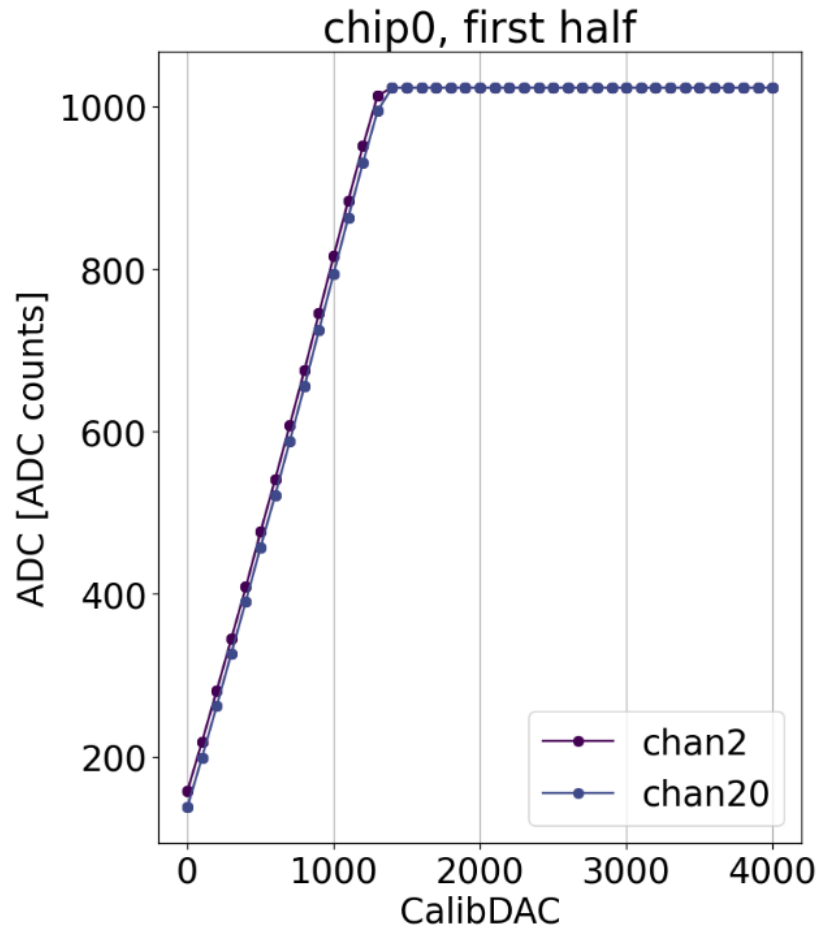
Internal Injection with 500 fC capacitor

12 bits DAC: 4096 : 500fC

1 Calib DAC: 0.122fC

1023-pedestal = 848 : 1340 Calib DAC & pedestal = 175

848 ADC:  $1340 * 0.122 = \sim 0.190 \text{ fC}$



**1 ADC unit = ~0.190 fC**

# Phase-II upgrades

The Large Hadron Collider (LHC) will see a second phase of high-luminosity operation that is expected to start in 2029.

The **High Luminosity Large Hadron Collider (HL-LHC)** will bring major challenges :

**Pile-up :**             $\sim 50 \rightarrow 140 - 200$

**Luminosity:**  $\sim 2 \times 10^{34} \rightarrow \sim 5 - 7 \times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$ .

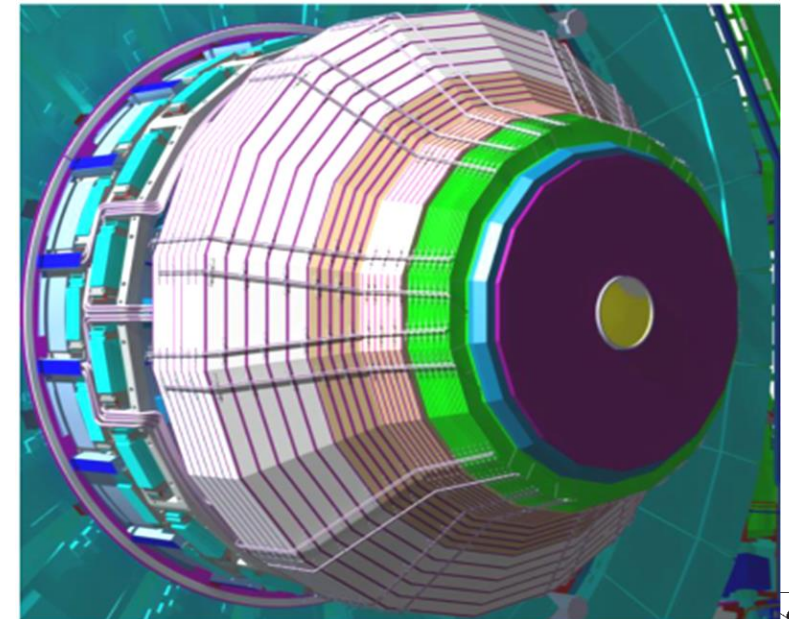
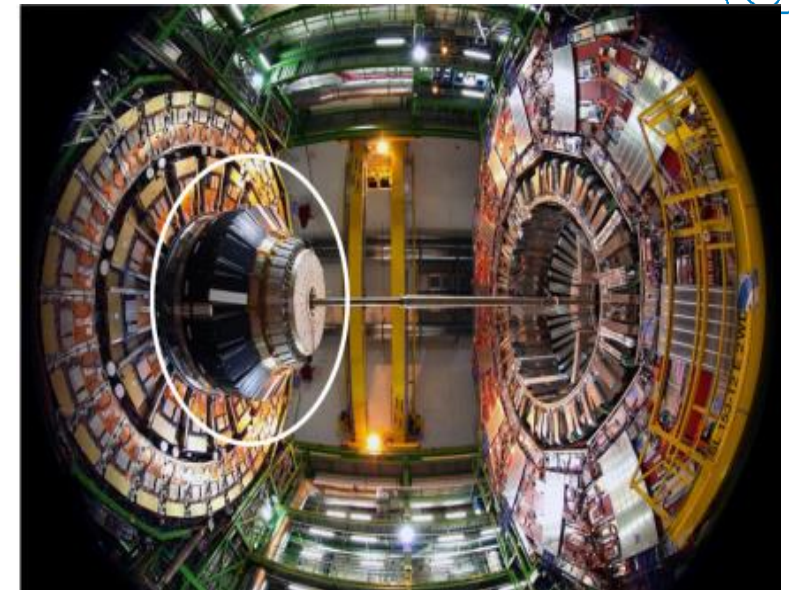
**Fluence:**  $\sim 10^{16} \text{ 1 MeV neq cm}^{-2}$  &  $\sim 2 \text{ MGy @end } 3000\text{fb}^{-1}$

To cope with these challenges

**Significant detector upgrades are planned...**

- **One very important and major upgrade is HGCAL**
- To replace Endcap Calorimeters ECAL ( $\text{PbWO}_4$  crystal) & HCAL (plastic scintillator) completely with new calorimeter, the **High-Granularity Calorimeter (HGCAL)**.

- **silicon and plastic scintillator mix**





# Introduction to HGCAL

The HGCAL is a 47-layer, sampling Calorimeter that will give 5D information (E,X,Y,Z, time) of incident particles

## Key parameters:-

Weight ~250 ton., coverage  $1.5 < \eta < 3.0$ , operating Temp :  $-30\text{ C}^0$ .

Two parts: **CE-E** (electromagnetic) & **CE-H** (hadronic)

Radiation environment: **2 MGy** &  **$8 \times 10^{15}$  n/cm<sup>2</sup>**

## Active materials:

~**620 m<sup>2</sup>** of Si in CE-E and high rad. zone of CE-H .

~**400 m<sup>2</sup>** of Scintillator tiles with SiPM in low-rad. region.

## Very granular

~**6M Si-channels** to be read out by ~**28K Si-Hex modules**.

Use the Front-end ASIC HGCROC for readout (designed by OMEGA) .

